

# **Technical Note**



# Motor Drivers for Printers System Driver for Ink Jet Printers

### BD64550EFV

No.10016EAT03

#### Description

This is 1-chip system motor driver integrating 2-channel H-bridge driver, step-down switching regulator with built-in power DMOS, series regulator and reset output.

#### Features

- 1) Low-on resistance output H-bridge driver (2-channel)
- 2) Constant-current chopping drive H-bridge driver
- 3) Switching regulator with built-in P-channel power DMOS FET
- 4) Soft start function: 23.6 ms (Typ.)
- 5) Reset release timer: 80 ms (Typ.)
- 6) 16 bit serial interface
- 7) Logic input interface (serial/parallel changeable)
- 8) Ultra thin type high heat dissipation HTSSOP-B40 package
- 9) Overcurrent protection in H-bridge driver block
- 10) Input voltage low voltage protection in H-bridge driver block
- 11) Overcurrent protection in switching regulator block
- 12) Output overvoltage protection in switching regulator block
- 13) Output low voltage protection in switching regulator block
- 14) Thermal shutdown

#### Applications

Inkjet printer, photo printer, etc.

#### ●Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
VM applied voltage	V <sub>M</sub>	40	V
Logic input voltage	VL	-0.4 ~ 5.5	V
RIN applied voltage	V <sub>RIN</sub>	5.5	V
RNF voltage	V <sub>RNF</sub>	0.5	V
Power dissipation	Pd	1600*	mW
Operating temperature range	T <sub>OPR</sub>	-25 ~ +85	°C
Storage temperature range	T <sub>STG</sub>	-55 ~ +150	°C
Junction temperature	T <sub>jmax</sub>	150	°C
Motor driver output current (peak 500 ns)	I <sub>omax</sub> (peak)	8.0	А
Motor driver output current (DC)	I <sub>omax</sub> (DC)	2.5**	А
Switching regulator output current (DC)	I <sub>omax</sub>	0.5	А
Series regulator output current (DC)	I <sub>omax</sub>	0.25	А

\* Reduced by 12.8 mW/°C over 25 °C, when mounted on a glass epoxy board (70 mm x 70 mm x 1.6 mm).

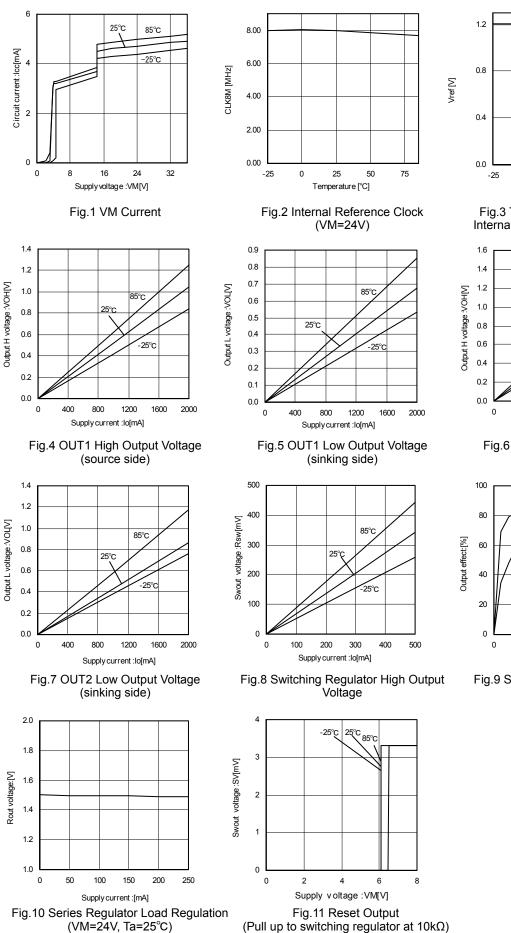
\*\* Must not exceed Pd or ASO.

#### Operating Conditions

Parameter	Symbol	Limit	Unit
VM operating power supply voltage range	V <sub>M</sub>	7 ~ 36	V
SCLK max. operating frequency	F <sub>SCLK</sub>	20	MHz
Switching regulator output voltage range	V <sub>swreg</sub>	3 ~ 5	V

#### ●Electrical Characteristics (Unless otherwise specified,Ta=25°C,V<sub>M</sub>=24V)

Parameter	Symbol	ol		1	Unit	Conditions	
	Cymbol	Min.	Тур.	Max.	onic	Contaitione	
Overall						1	
VM current 1	I <sub>VM1</sub>	-	-	8	mA	V <sub>M</sub> =7V	
VM current 2	I <sub>VM2</sub>	-	-	12	mA	V <sub>M</sub> =24V	
I-bridge 1						1	
Output on resistance (source side))	R <sub>ONH1</sub>	-	0.6	0.78	Ω	I <sub>o</sub> =1A	
Output on resistance (sinking side)	R <sub>ONL1</sub>	-	0.4	0.52	Ω	I <sub>o</sub> =1A	
Output leak current	I <sub>LEAK1</sub>	0	-	10	μA	V <sub>M</sub> =36V	
Built-in diode forward direction voltage (source side)	V <sub>FH1</sub>	0.6	0.9	1.2	V	I <sub>o</sub> =1A	
Built-in diode forward direction voltage (sinking side) <b>I-bridge 2</b>	$V_{FL1}$	0.6	0.9	1.2	V	I <sub>o</sub> =1A	
Output on resistance (source side)	R <sub>ONH2</sub>	-	0.7	0.91	Ω	I <sub>o</sub> =1A	
Output on resistance (sinking side)	R <sub>ONL2</sub>	-	0.5	0.65	Ω	I <sub>o</sub> =1A	
Output leak current	I <sub>LEAK2</sub>	0	-	10	μA	V <sub>M</sub> =36V	
Built-in diode forward direction voltage (source side)	V <sub>FH2</sub>	0.6	0.9	1.2	V	I <sub>o</sub> =1A	
Built-in diode forward direction voltage (sinking side)	$V_{FL2}$	0.6	0.9	1.2	V	I <sub>o</sub> =1A	
Current control							
VREF voltage range	$V_{REF}$	0.8	-	3.5	V		
VREF pin outflow current	I <sub>REF</sub>	-	0	1	μA		
RNF pin outflow current	I <sub>RNF</sub>	5	15	30	μA		
RNFS pin outflow current	I <sub>RNFS</sub>	-	0	1	μA		
VREF-RNFS offset voltage	VOFFSET	-15	0	15	mV	VREF=2V	
Control logic							
High input voltage	VINH	2.0	-	5.5	V		
Low input voltage	V <sub>INL</sub>	0	-	0.8	V		
Input current	I <sub>IN</sub>	21	33	45	μA	Input voltage=3.3V	
Switching power source							
DSEN threshold voltage	V <sub>SWBIAS</sub>	0.873	0.9	0.927	V		
Output on resistance	Rswon	-	0.8	1.04	Ω	At I <sub>o</sub> =250mA	
Leak current	I <sub>SWLEAK</sub>	0	_	10	μA	V <sub>M</sub> =36V	
DUTY_MAX value	D <sub>MAX</sub>	-	92	-	%		
Clock frequency	F <sub>SW</sub>	130	200	270	kHz		
DSEN pin outflow current	I <sub>DSEN</sub>	-	0	1	μA		
Series power source							
Output voltage	V <sub>SOUT</sub>	1.425	1.5	1.575	V	At I <sub>o</sub> =70mA	
Leak current	I <sub>SLEAK</sub>	0	-	10	μA		
RESET pin							
Output voltage	V <sub>RSTL</sub>	0	-	0.2	V	I <sub>DRAIN</sub> =1mA	
Leak current	IRSTLEAK	0	-	10	μA		
High VM threshold voltage	V <sub>MPORH</sub>	6.3	6.5	6.7	V	$V_{M}$ at power on	
Low VM threshold voltage	VMPORL	5.9	6.1	6.3	V	$V_M$ at power off	
High motor UVLO voltage	V <sub>MMTH</sub>	13.5	15	16.5	V	Off motor only	
Low motor UVLO voltage	V <sub>MMTL</sub>	12.5	14	15.5	V		
Reset delay time	T <sub>POR</sub>	50	80	110	ms		



0.8 0.4 0.0 -25 0 25 50 75 Temperature (°C)

Fig.3 Temperature dependence of Internal Standard Voltage (VM=24V)

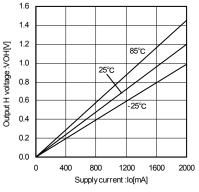


Fig.6 OUT2 High Output Voltage (source side)

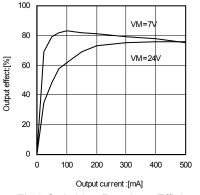


Fig.9 Switching Regulator Efficiency (Ta=25°C)

#### Block Diagram, Application Circuit Diagram, and Pin Function

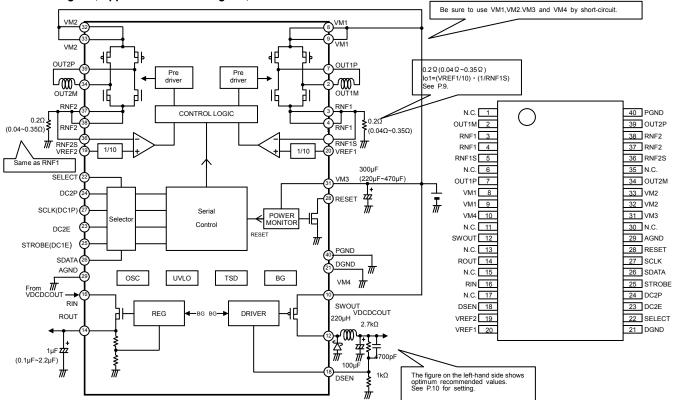


Fig.12 Block Diagram and Application Circuit Diagram

Fig.13 Pin Assignment Diagram

No.	Pin name	Function	No.	Pin name	Function	
1	NC	Non Connection	21	DGND	Digital GND	
2	OUT1M	H-bridge output pin 1M	22	SELECT	Input pin select pin	
3	RNF1	Output current detection pin 1	23	DC2E	H-bridge 2 side enable input pin	
4	RNF1	Output current detection pin 1	24	DC2P	H-bridge 2 side phase pin	
5	RNF1S	Output current detection input pin	25	STROBE	Serial port strobe input pin /	
6	NC	Non Connection	25	SIRUBE	H-bridge 1 side enable pin	
7	OUT1P	H-bridge output pin 1P	26	SDATA	Serial port data input pin	
8	VM1	Motor power supply pin	27	SCLK	Serial port clock input pin /	
9	VM1	Motor power supply pin	21	SOLK	H-bridge 1 side phase input pin	
10	VM4	Switching regulator power supply pin	28	RESET	Reset signal output pin	
11	NC	Non Connection	29	AGND	ANALOG GND	
12	SWOUT	Switching regulator output pin	30	NC	Non Connection	
13	NC	Non Connection	31	VM3	Power supply pin	
14	ROUT	Series regulator output pin	32	VM2	Motor power supply pin	
15	NC	Non Connection	33	VM2	Motor power supply pin	
16	RIN	Series regulator power supply pin	34	OUT2M	H-bridge output pin 2M	
17	NC	Non Connection	35	NC	Non Connection	
18	DSEN	Switching regulator voltage sense pin	36	RNF2S	Output current detection input pin	
19	VREF2	Reference voltage input pin	37	RNF2	Output current detection pin 2	
20	VREF1	Reference voltage input pin	38	RNF2	Output current detection pin 2	
			39	OUT2P	H-bridge output pin 2P	
			40	PGND	POWER GND	

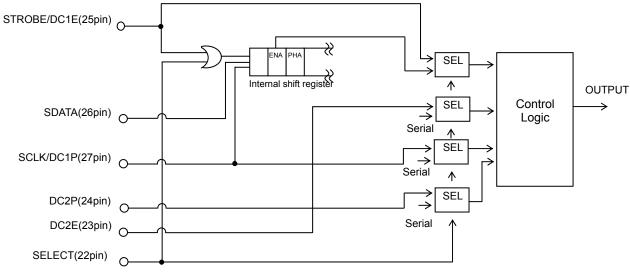
\* Precaution regarding VM pin

If you use VM1, VM2, VM3 and VM4 not by short-circuit, they may be destroyed. Be sure to use them by short-circuit. And be sure to set up a bypass capacitor (220μF to 470μF) closer to VM3 pin as much as possible.

#### Pin selection function

Either serial control or external PWM control can be selected for motor control type with SELECT pin (pin 22).

SELECT	Output state
L	Serial input mode
Н	External PWM control mode



#### Fig.14 Serial Input Block Diagram

#### The input/output logic at SELECT = H is as follows.

DC1E/DC2E	Output state		
L	Open		
Н	ACTIVE		
DC1P/DC2P	OUTP	OUTM	
L	SINK	SOURCE	

#### OProcedure of DC motor drive by external PWM control

SOURCE

#### 1)Serial setting

Н

- Set the serial by SELECT pin = L. (WORD\_S and WORD\_D setting)
  - WORD\_S (see P.7) is a drive parameter for setting OFF\_TIME, BLANK TIME etc.

SINK

• WORD\_D (see P.7) is for drive setting to set drive mode of each H-bridge. When setting WORD\_D (see P.7), make sure that ENABLE signal (ENABLE\_1, ENABLE\_2) of serial bit is L. If ENABLE signal is H, the motor may operate. Input of DC2P pin can be either H or L.

2) External PWM drive mode switch

Set external PWM drive mode by SELECT pin = H. Switch by DC1E (STROBE)/CD2E pin = L when switching SELECT pin.

3)Drive

PHASE, ENABLE pin input signal (DC1E/DC1P/DC2E/DC2P) drives in external PWM mode.

#### Serial interface

16-bit 3-linear type serial interface (SDATA (pin 26), SCLK (pin 27), STROBE (pin 25)) is provided to set the operation and the value of current limit. Data are sent to the internal shift register by falling edge of SCLK pin in the area L of STROBE pin. Data of shift register are written in an appropriate address of internal memory of 2\*15 bits by rising edge of STROBE pin according to address data of D15. The input order of serial data is from D0 to D15.

#### Address data

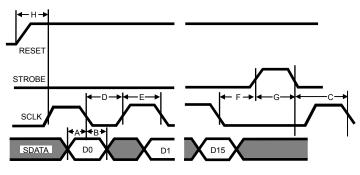
D15	Word select
0	WORD_S
1	WORD_D

#### Memory data allocation

BIT	WORD_S	Default	WORD_D	Default
D0	Rohm_Reserve[2]	0	Rohm_Reserve[11]	0
D1	Rohm_Reserve[1]	0	Rohm_Reserve[10]	0
D2	Rohm_Reserve[0]	0	Rohm_Reserve[9]	0
D3	OFF TIME_2[2]	0	Rohm_Reserve[8]	0
D4	OFF TIME_2[1]	0	Rohm_Reserve[7]	0
D5	OFF TIME_2[0]	0	Rohm_Reserve[6]	0
D6	BLANK TIME_2[1]	0	Rohm_Reserve[5]	0
D7	BLANK TIME_2[0]	0	Rohm_Reserve[4]	0
D8	OFF TIME_1[2]	0	Rohm_Reserve[3]	0
D9	OFF TIME_1[1]	0	PWM_MODE_2	0
D10	OFF TIME_1[0]	0	S_PHASE_2	0
D11	BLANK TIME_1[1]	0	S_ENABLE_2	0
D12	BLANK TIME_1[0]	0	PWM_MODE_1	0
D13	MASK SELECT	0	S_PHASE_1	0
D14	SWOFF	0	S_ENABLE_1	0

The timing of serial report writing is shown in the right figure. And the minimum timing of each is as follows:

A : SDATA setup time · · · · · · · · · · · · · · · · · · ·	10nsec
B : SDATA hold time · · · · · · · · · · · · · · · · · · ·	10nsec
C : Setup STROBE to SCLK falling edge · ·	50nsec
D : SCLK low pulse width · · · · · · · · · · · · · · · · · · ·	25nsec
E : SCLK High pulse width · · · · · · · · · · · · · · · · · · ·	25nsec
F : Setup SCLK falling edge to STROBE ····	25nsec
G : STROBE pulse width · · · · · · · · · · · · · · · · · · ·	50nsec
H : Setup RESET to SCLK Rising ······	50µsec



ORESET signal is an internal RESET signal and generated inside IC at the same timing of external RESET output. OSTROBE, SCLK and SDATA signals are input signals through external ASIC.

Fig.15 Serial Signal Input Timing

#### Serial Port Explanation

WORD\_S

OSWOFF

Set on/off of switching regulator circuit.		
0	Switching regulator on	
1	Switching regulator off	

#### OMASK SELECT

Common mask can be provided to 2-phase H-bridge drive noise mask (BLANK time).

0	Independent mask on single-phase/two-phase.
1	Common mask on single-phase/two-phase.

#### **OBLANK TIME**

Current-limit comparator monitors RNF pin voltage to set limit to current, but during the period from switching on to BLANK TIME, detection becomes invalid in order to avoid wrong detection caused by spike noise that happens at the time of switching on. See P.8 for details.And during the period from ENABLE signal on to BLANK TIME at switching of PHASE signal, detection becomes invalid as well.

[1]	[0]	BLANK TIME	Unit
0	0	2.0	μs
0	1	3.0	μs
1	0	4.0	μs
1	1	5.0	μs

#### OOFF TIME

Set current decay time.

[2]	[1]	[0]	OFF TIME	Unit
0	0	0	6	μs
0	0	1	8	μs
0	1	0	10	μs
0	1	1	12	μs
1	0	0	14	μs
1	0	1	16	μs
1	1	0	18	μs
1	1	1	20	μs

#### WORD\_D

Each bridge on/off signal. Output state is as follows.

	Output state	
0	Open	
1	ACTIVE	

#### OS\_PHASE\_1/S\_PHASE\_2

Set the direction of current of each bridge. Output state is as follows.

	Р	М	
0	SINK	SOURCE	
1	SOURCE	SINK	

#### OPWM\_MODE\_1/PWM\_MODE\_2

Set current decay mode in bridge1 and 2. (See page 8 for details about each mode.)

0	FAST DECAY
1	SLOW DECAY

(※)Rohm\_Reserve

Rohm\_Reserve is special mode setting port for inspection at shipment. Especially, if Rohm Reserve [3], [4], [5], [7], [8], [9], [10], [11] is set to H by mistake, malfunction may be caused. Be sure not to set.

OS\_ENABLE\_1/S\_ENABLE\_2

#### H-bridge Driver Operation

This IC has built-in 2-channel H-bridge driver.

Each can be used for DC motor drive independently.

- 1. Current setting
- Motor output current-limit value can be set according to the equation below. Io=(VREF/10) • (1/RNFS) [A] Decide within the range VREF = 0.91/ to 2.51/ RNFS = 0.040 to 0.250
- Decide within the range VREF = 0.8V to 3.5V, RNFS =  $0.04\Omega$ to  $0.35\Omega$ .
- 2. DECAY mode
  - Current decay mode can be selected from serial input at the time of motor chopping drive. Each mode and timing is as follows.

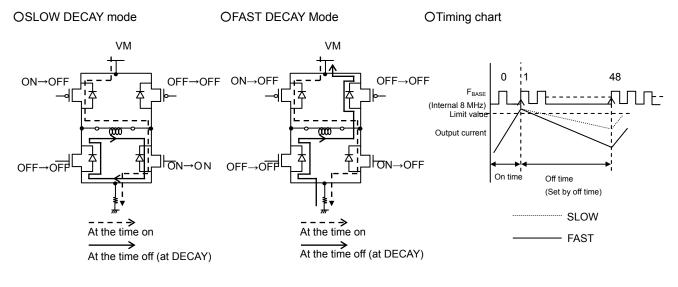


Fig.16 On/Off Timing at SLOW Fig.17 On/Off Timing at FAST

Fig.18 DECAY Mode Timing Chart

3. Protection area for output current value wrong detection

In order to avoid wrong detection of current detection comparator by varistor current element in each motor, current detection are masked at the timing as follows.

①PHASE switching time

②ENABLE on time

③When output is on after OFF\_TIME is finished at the time of current chopping drive

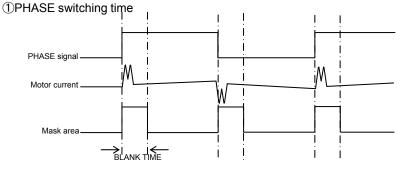


Fig.19 Timing Chart of PHASE Switching Time

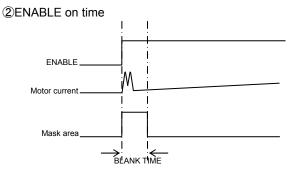


Fig.20 Timing Chart of ENABLE On Timing

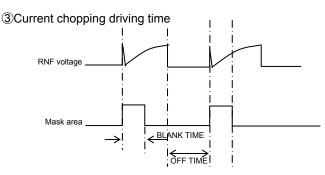


Fig.21 Timing Chart of Current Chopping Driving Time

#### •Switching regulator operation

#### OBasic operation

A switching regulator circuit that repeats on/off being synchronized with internal CLK (200 KHz) is built-in.

The start up output voltage SWOUT (pin 12) becomes up and run step by step with soft start at the VM power-on (VM $\geq$ V<sub>MPORH</sub>). The output voltage is determined by the equation below with external resistance.

VOUTDCDC=VBIAS · {(R1+R2)/R2 } [V]

The setting should be performed so that the switching regulator output voltage (VOUTDCDC) waveform is optimized within the range of VOUTDCDC = 3V to 5V, VBIAS = 0.9V (Typ.), R1 + R2 =  $1k\Omega$  to  $10k\Omega$ , C1 = 1,000pF to 10,000pF.

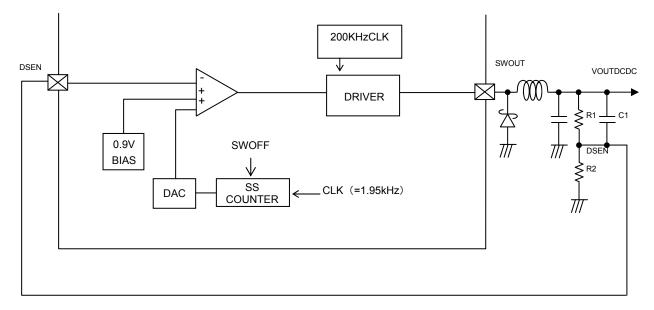
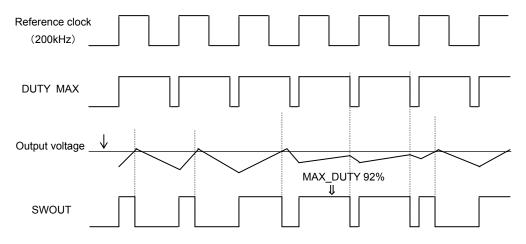
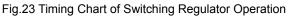


Fig.22 Switching Regulator Block Diagram





#### OSoft start

As shown in Fig.24, VOUTDCDC output voltage becomes up and run step by step with soft start at the time of power-on.

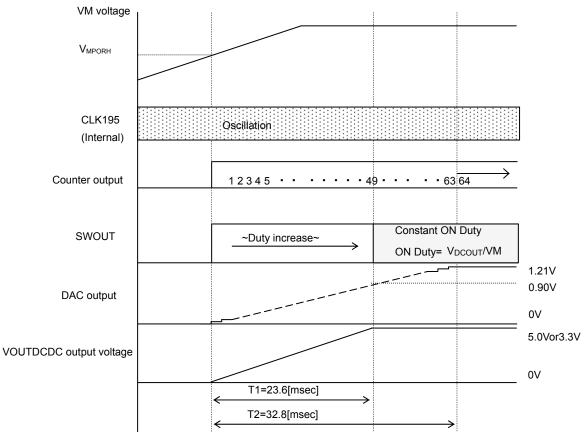


Fig.24 Soft Starting Time Timing Chart

This soft start method is realized by changing comparator positive side voltage that determines output duty of switching regulator to linear using DAC.

Soft start time T1 is constant value regardless of VM voltage. Soft start time T1=23.6msec(typ.)

	<u>p.)</u>
Count finish time <u>T2=32.8msec(type</u>	p.)

OSeries regulator operation

Inputting switching regulator output into RIN pin (pin 16) enables to drive series regulator circuit.

At the time of power-on, output voltage start up step by step with soft starting at the same timing as switching regulator circuit.<sup>A</sup>Soft start time is 23.6ms (Typ.).

Regarding external capacitor of ROUT pin (pin 14), it works normally without setting. But switching noise of switching regulator becomes easy to get in due to dragging on board pattern and the like. Pay attention to switching noise.

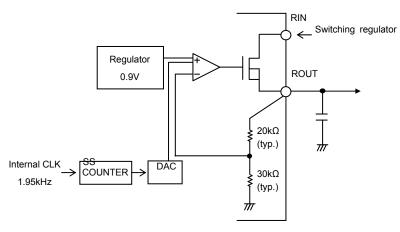


Fig.25 Series Regulator Block Diagram

#### Protection function

OProtection circuit function

Overall	Overheating protection
DC motor drive circuit	Overcurrent protection
Switching regulator circuit	Overcurrent protection, output overvoltage protection, output low voltage protection
Series regulator circuit	None

OOperation at protection circuit operation

①Overheating protection · · · All functions are shutout along with junction temperature rise

Т	Thermal shutdown temperature	175°C(typ.)
---	------------------------------	-------------

	Switching regulator	Series regulator	DC motor	RESET	Re-start
At protection operation	OFF	OFF	OFF	L	Again power-on

②Overcurrent protection (Switching regulator)

	Set current	Mask time	State after operation
I <sub>SWOC</sub>	2.6(A)	0.5µsec <sup>(</sup> *)	All function shutout

	Switching regulator	Series regulator	DC motor	RESET	Re-start
Operating	OFF	OFF	OFF	L	Again power-on

③Overcurrent protection (DC motor)

	Set current	Mask time	State after operation
IDCOC	3.8(A)	1.5µsec	Shown below

	Switching regulator	Series regulator	DC motor	RESET	Re-start
Operating	ON	ON	OFF	L_PULSE	Serial re-input

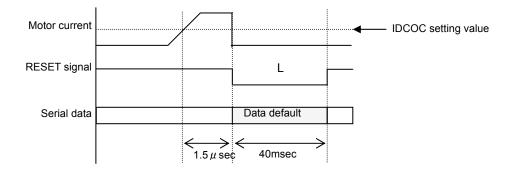


Fig.26 Timing Chart of Motor Overcurrent Protection

(X) If the output pulse of switching regulator is 0.5µs or below, the overcurrent function does not operate even at the time of overcurrent outflow.

#### (4)Low voltage protection/overvoltage protection circuit

All functions are shutout on the condition of setting value (+30%, -30%) while DSEN pin voltage (pin 18) of switching regulator circuit is monitored.

	Set voltage	Mask time State after operation	
VSWLV	0.60(V)	10µsec	All function shutout
VSWOH	1.20(V)	10µsec	All function shutout

Note that output overvoltage and output low voltage protection does not work until soft start count finish (32.8 ms, Typ.) at the time of start up of DC/DC power after power-on.

	Switching regulator	Series regulator	DC motor	RESET	Re-start
Operating	OFF	OFF	OFF	L	Again power-on

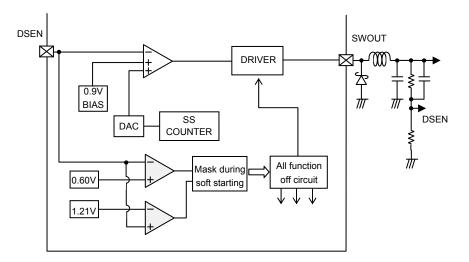


Fig.27 Switching Regulator Block Diagram

#### **ORESET** function

#### Power-on RESET circuit is built-in for VM power source.

H is output at RESET pin through DELAY time of internal counter when power voltage goes up to  $V_{MPORH}$  (6.5 V, Typ.) or higher at the time of power-on. In addition, hysteresis is set up at the time of power-down to output L at RESET pin with VMPORL (6.1 V, Typ.) And no response time (2.5µs, Typ.) of voltage detection is set in order to avoid wrong detection by sudden power-off.If protection circuits other than overcurrent protection of motor starts operating, RESET is not released if VM power is not on again.

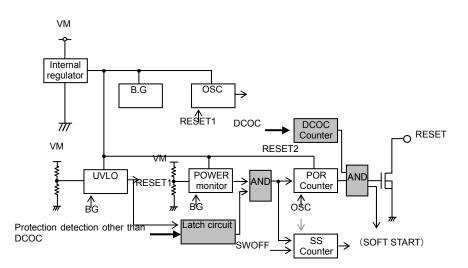


Fig.28 RESET Internal Circuit Block Diagram

●I/O Circuit Diagram

## 1 OUT1P, OUT1M, OUT2P, OUT2M, RNF1 and RNF2 2 RNF1S and RNF2S ₩ VM1, VM2 -d $\overline{\Lambda}$ b-OUT1P, OUT2P --⊳ out1m, out2m 4 RNF1S, RNF2S Ąφ 77 777 Overcurrent protection circuit −D RNF1, RNF2 ⇒ 15µÅ(TYP.) $\overline{}$ 3 SWOUT ④ RIN and ROUT $\triangleleft_{\mathsf{RIN}}$ . VM4 /ROUT SWOUT $\triangle$ $\frac{1}{7}$ 77 $\pi$ 777 5 DSEN D DSEN ₥ ₥ 77 ⑦ Logic input ⑥ VREF1 and VREF2 **8** RESET –⊳ RESET D 7 777 $\pi$

Fig.29 I/O Circuit

#### Power Dissipation Reduction

On the backside of HTSSOP-B40 package, metal is filled in. Heat dissipation is possible by letting in a through hole from backside. Power dissipation can be improved by providing heat dissipation pattern of copper foil or the like not only on the board surface but also on the backside. The metal on the backside shorts with the backside of IC tip and the potential is GND. Therefore, avoid shorts with other potential than GND, or malfunction or destruction may happen. It is recommended that backside metal should short with GND by soldering.

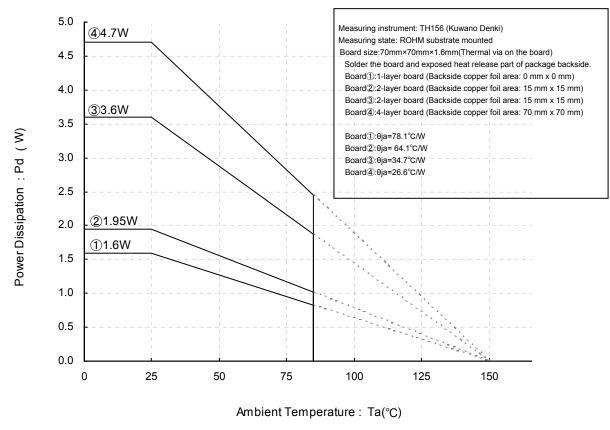


Fig.30 Power Dissipation Reduction

#### Notes for Use

1) Absolute maximum ratings

Use of the IC in excess of absolute maximum ratings such as the applied voltage or operating temperature range may result in IC damage. Assumptions should not be made regarding the state of the IC (short mode or open mode) when such damage is suffered. A physical safety measure such as a fuse should be implemented when use of the IC in a special mode where the absolute maximum ratings may be exceeded is anticipated.

- 2) Connecting the power supply connector backward Connecting the power supply connector backwards may result in damage to the IC. Insert external diodes between the power supply and the IC's power supply pins as well as the motor coil to protect against damage from backward connections.
- 3) Power supply lines

As return of current regenerated by back EMF of motor happens, take steps such as putting capacitor between power supply and GND as a electric pathway for the regenerated current. Be sure that there is no problem with each property such as emptied capacity at lower temperature regarding electrolytic capacitor to decide capacity value. If the connected power supply does not have sufficient current absorption capacity, regenerative current will cause the

voltage on the power supply does not nave sufficient current absorption capacity, regenerative current will cause the absolute maximum ratings. It is recommended to implement a physical safety measure such as the insertion of a voltage clamp diode between the power supply and GND pins.

#### 4) GND potential

Ensure a minimum GND pin potential in all operating conditions.

#### 5) Setting of heat

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions. BD64550EFV expose its frame of the backside of package. Note that this part is assumed to use after providing heat dissipation treatment to improve heat dissipation efficiency. Try to occupy as wide as possible with heat dissipation pattern not only on the board surface but also the backside.

6) Pin short and mistake fitting

Use caution when orienting and positioning the IC for mounting on printed circuit boards. Improper mounting may result in damage to the IC. Shorts between output pins or between output pins and the power supply and GND pins caused by the presence of a foreign object may result in damage to the IC.

7) Actions in strong magnetic field

Use caution when using the IC in the presence of a strong magnetic field as doing so may cause the IC to malfunction.

8) ASO

When using the IC, set the output transistor so that it does not exceed absolute maximum ratings or ASO.

9) Thermal shutdown circuit

The IC has a built-in thermal shutdown circuit (TSD circuit). If the chip temperature becomes Tjmax=150°C, and higher, coil output to the motor and regulator output will be OFF, and reset output will be L. The TSD circuit is designed only to shut the IC off to prevent runaway thermal operation. It is not designed to protect or indemnify peripheral equipment. Do not use the TSD function to protect peripheral equipment.

10)Testing on application boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Ground the IC during assembly steps as an antistatic measure, and use similar caution when transporting or storing the IC. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process.

#### 11) Regarding input pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated/N junctions are formed at the intersection of these P layers with the N layers of other elements to create a variety of parasitic elements. For example, when a resistor and transistor are connected to pins as shown in Fig. 31,

Othe P/N junction functions as a parasitic diode

when GND > (Pin A) for the resistor or GND > (Pin B) for the transistor (NPN).

OSimilarly, when GND > (Pin B) for the transistor (NPN), the parasitic diode described above combines

with the N layer of other adjacent elements to operate as a parasitic NPN transistor.

The formation of parasitic elements as a result of the relationships of the potentials of different pins is an inevitable result of the IC's architecture. The operation of parasitic elements can cause interference with circuit operation as well as IC malfunction and damage. For these reasons, it is necessary to use caution so that the IC is not used in a way that will trigger the operation of parasitic elements, such as by the application of voltages lower than the GND (P substrate) voltage to input pins.

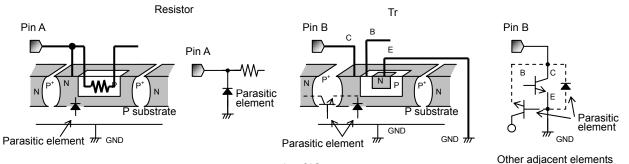
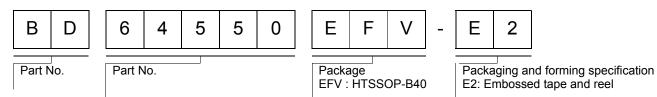


Fig.31 example of IC structure

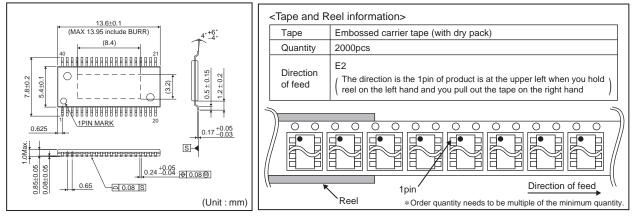
12)Ground Wiring Pattern

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the application's reference point so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring pattern of any external components, either.

#### Ordering Part Number



#### HTSSOP-B40



	copying or reproduction of this document, in part or in whole, is permitted without the nsent of ROHM Co.,Ltd.
Th	e content specified herein is subject to change for improvement without notice.
"Pi	e content specified herein is for the purpose of introducing ROHM's products (hereinafte roducts"). If you wish to use any such Product, please be sure to refer to the specifications ich can be obtained from ROHM upon request.
illu	amples of application circuits, circuit constants and any other information contained hereir strate the standard usage and operations of the Products. The peripheral conditions mus taken into account when designing circuits for mass production.
Но	eat care was taken in ensuring the accuracy of the information specified in this document wever, should you incur any damage arising from any inaccuracy or misprint of such ormation, ROHM shall bear no responsibility for such damage.
exa im oth	e technical information specified herein is intended only to show the typical functions of and amples of application circuits for the Products. ROHM does not grant you, explicitly o plicitly, any license to use or exercise intellectual property or other rights held by ROHM and her parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the e of such technical information.
eq	e Products specified in this document are intended to be used with general-use electronic uipment or devices (such as audio visual equipment, office-automation equipment, commu sation devices, electronic appliances and amusement devices).
Th	e Products specified in this document are not designed to be radiation tolerant.
	nile ROHM always makes efforts to enhance the quality and reliability of its Products, a oduct may fail or malfunction for a variety of reasons.
ag fai sh	ease be sure to implement in your equipment using the Products safety measures to guard ainst the possibility of physical injury, fire or any other damage caused in the event of the lure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM all bear no responsibility whatsoever for your use of any Product outside of the prescribed ope or not in accordance with the instruction manual.
sys ma ins co of	e Products are not designed or manufactured to be used with any equipment, device o stem which requires an extremely high level of reliability the failure or malfunction of which ay result in a direct threat to human life or create a risk of human injury (such as a medica trument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel- ntroller or other safety device). ROHM shall bear no responsibility in any way for use of any the Products for the above special purposes. If a Product is intended to be used for any ch special purpose, please contact a ROHM sales representative before purchasing.
be	you intend to export or ship overseas any Product or technology specified herein that may controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to tain a license or permit under the Law.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

## ROHM Customer Support System

http://www.rohm.com/contact/



Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию.

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России, а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научноисследовательскими институтами России.

С нами вы становитесь еще успешнее!

#### Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург, Промышленная ул, дом № 19, литера Н, помещение 100-Н Офис 331